NSN 5962-01-240-5595

Memory Microcircuit - Page 1 of 1



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Features Provided:
Burn in and programmable
Inclosure Material:
Silicon
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Voltage Rating And Type Per Characteristic:
2.4 volts high level output
Memory Device Type:
Prom
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0